## NSN 5961-01-009-4956

Transistor - Page 1 of 1

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-009-4956 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 15.0 collector to base voltage/static/emitter open and 15.0 collector to emitter voltage/static/base open and 4.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 30.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 200.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 4 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/511 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**